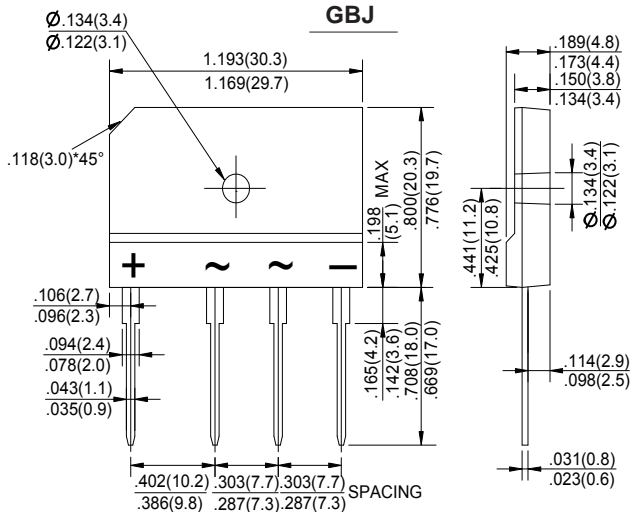




# GBJ15005 THRU GBJ1510

## SILICON BRIDGE RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 15.0 Amperes



Dimensions in inches and (milimeters)

### FEATURES

- ◆ Rating to 1000V PRV
- ◆ Ideal for printed circuit board
- ◆ Low forward voltage drop, high current capability
- ◆ Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ◆ The plastic material has U/L flammability classification 94V-0

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	GBJ 15005	GBJ 1501	GBJ 1502	GBJ 1504	GBJ 1506	GBJ 1508	GBJ 1510	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	VOLTS
Maximum Average Forward Rectified Current @ $T_C = 100$ (with heatsink Note 2) (without heatsink)	$I_{(AV)}$	15.0 3.7							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	240							Amps
Maximum instantaneous forward voltage drop per bridge element at 7.5A	$V_F$	1.0							Volts
Maximum DC reverse current at rated DC blocking voltage $T_A = 25^\circ C$ $T_A = 125^\circ C$	$I_R$	10							$\mu A$
		0.5							mA
It Rating for Fusing ( $t < 8.3ms$ )	$I^2 t$	240							$A^2 s$
Typical Junction Capacitance (Note 1)	$C_J$	60							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	0.8							$^\circ C/W$
Operating junction temperature range	$T_J$	-55 to +150							$^\circ C$
storage temperature range	$T_{STG}$	-55 to +150							$^\circ C$

NOTES: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
2. Device mounted on 75mm\*75mm\*1.6mm Cu plate heatsink.  
3. The typical data above is for reference only(典型值仅供参考).



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# RATINGS AND CHARACTERISTIC CURVES GBJ15005 THRU GBJ1510

FIG.1-FORWARD CURRENT DERATING CURVE

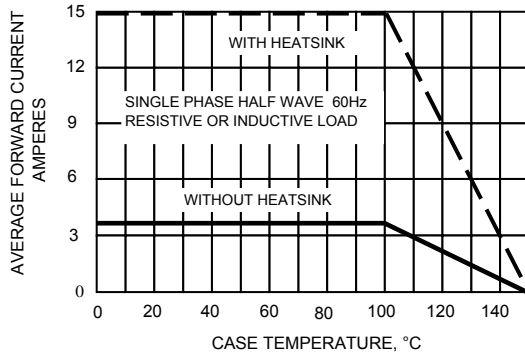


FIG.2-MAXMUN NON-REPETITIVE  
SURGE CURRENT

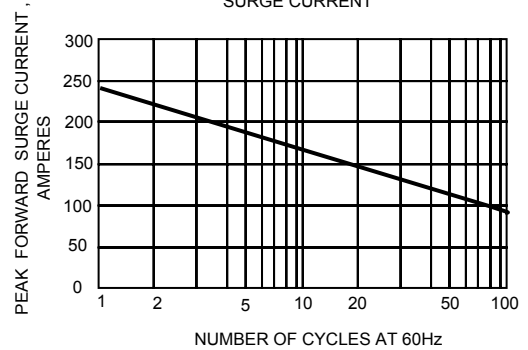


FIG.3-TYPICAL JUNCTION CAPACITANCE

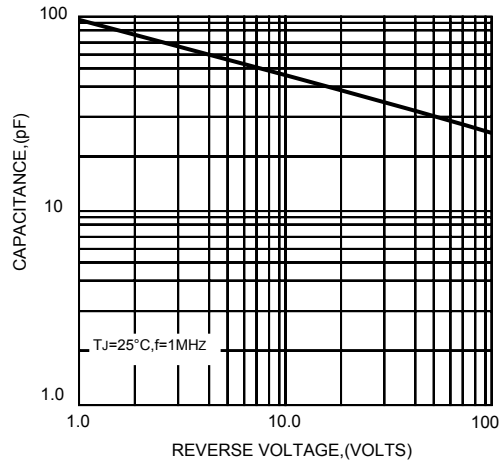


FIG.4-TYPICAL FORWARD CHARACTERISTICS

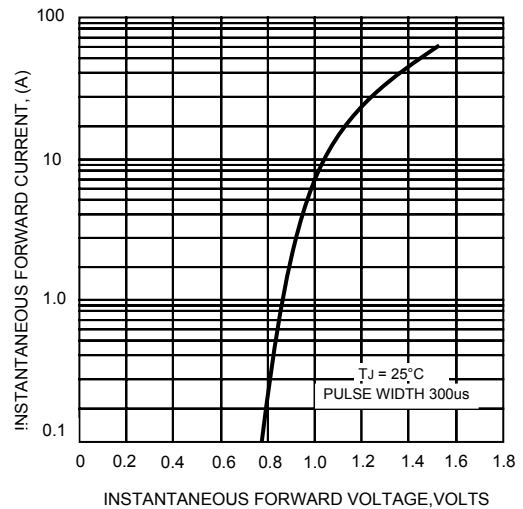
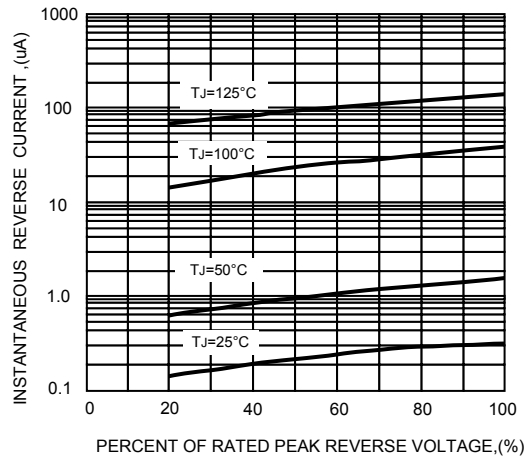


FIG.5-TYPICAL REVERSE CHARACTERISTICS



The cruve graph is for reference only, can't be the basis for judgment( )!



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